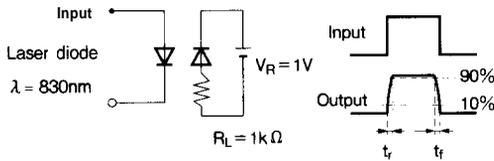


■ Electro-optical Characteristics

(T_a = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Reverse voltage	V _R	I _R = 10 μA	30	—	—	V
Dark current	I _d	V _R = 1V	—	—	2.0	nA
Short circuit current	*1 I _L	V _R = 1V, E _v = 1000 lx	8	13	—	μA
Short circuit current difference	ΔI _L /I _L	*2	—	—	±2	%
Terminal capacitance	C _t	V _R = 1V, f = 1MHz	—	15	30	pF
Peak sensitivity wavelength	λ _p	—	—	940	—	nm
Response time	*3 t _r , t _f	V _R = 1V, R _L = 1kΩ	—	15	30	μs
Resistance between electrode	R _{ie}	V _R = 1V, V _a = 0.5V	300	450	600	kΩ
Error of position detection	*4 —	—	—	—	±25	μm
Sensitivity	R	—	—	0.5	—	A/W

- *1 I_L = I₁ + I₂
However, I₁ and I₂ are collector current of A1 and A2.
E_v: Illuminance by CIE standard light source A (tungsten lamp)
- *2 ΔI_L = I₁ - I₂
- *3 Test circuit for response time is shown below.



- *4 75% area from detecting portion center to the edge of detecting portion
Definition of error of position detection:

Error of position detection of each incident light position defines the following formula if electrical center position is I₁ = I₂.

$$\text{Error of position detection (}\mu\text{m)} = \frac{L}{2} \times \frac{I_1 - I_2}{I_1 + I_2} - \text{incident light position (}\mu\text{m)}$$

L: Length of light detector surface

Fig. 1 Spectral Sensitivity

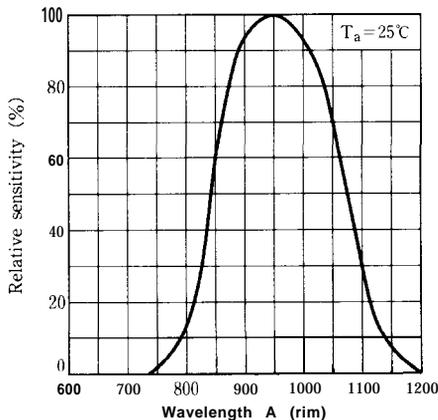


Fig. 2 Dark Current vs. Ambient Temperature

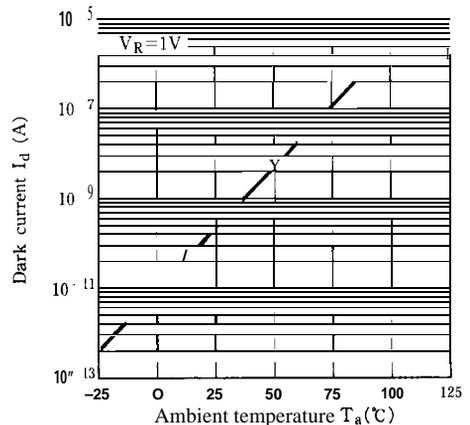


Fig. 3 Dark current vs. Reverse Voltage

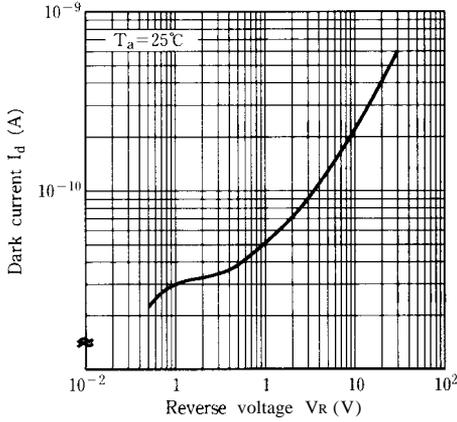


Fig. 4 Terminal Capacitance vs. Reverse Voltage

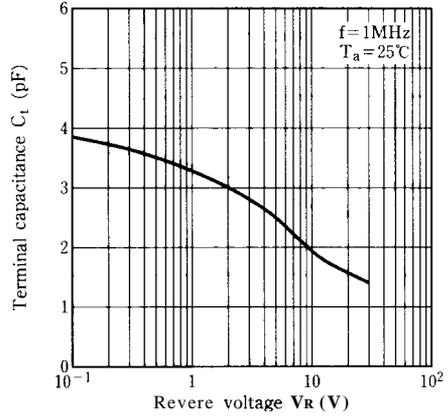


Fig. 5 Relative Output vs. Ambient Temperature

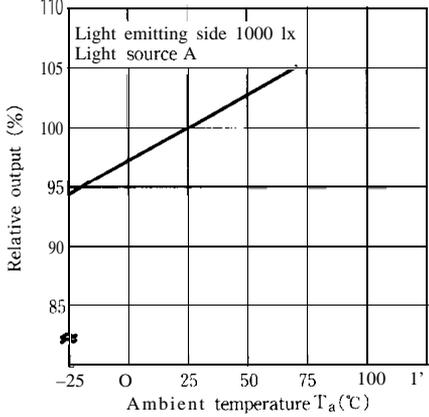


Fig. 6 Collector Current vs. Illuminance

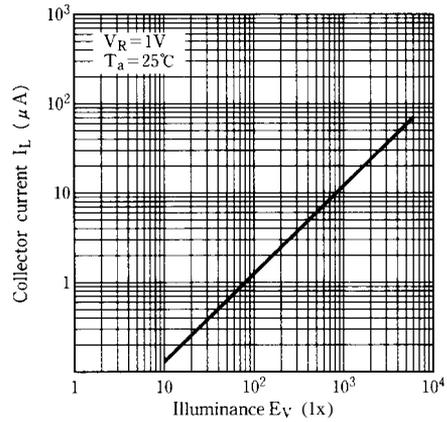


Fig. 7 Response Time vs. Load Resistance

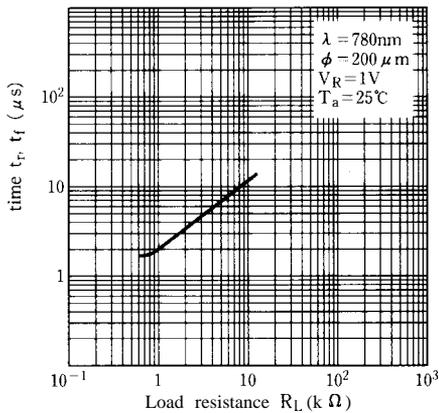
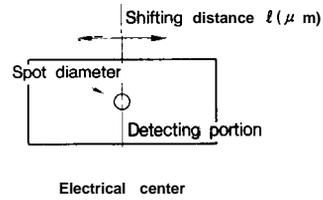
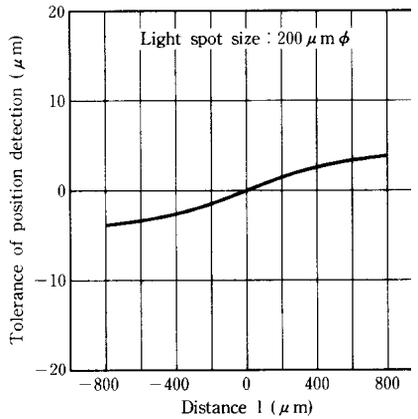


Fig. 8 Tolerance of Position Detection vs. Distance

- Please refer to the chapter "Precautions for Use" (Page 78 to 93)